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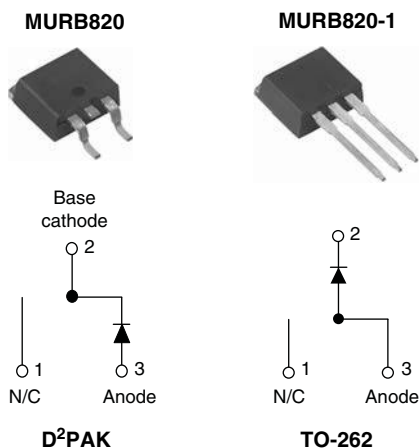
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## Ultrafast Rectifier, 8 A FRED P<sub>t</sub><sup>™</sup>



### FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- Designed and qualified for industrial level

### DESCRIPTION/APPLICATIONS

MUR.. series are the state of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, dc-to-dc converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

### PRODUCT SUMMARY

$t_{rr}$	25 ns
$I_{F(AV)}$	8 A
$V_R$	200 V

### ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Peak repetitive reverse voltage	$V_{RRM}$		200	V
Average rectified forward current	$I_{F(AV)}$	Total device, rated $V_R$ , $T_C = 150\text{ °C}$	8	A
Non-repetitive peak surge current	$I_{FSM}$		100	
Peak repetitive forward current	$I_{FM}$	Rated $V_R$ , square wave, 20 kHz, $T_C = 150\text{ °C}$	16	
Operating junction and storage temperatures	$T_J, T_{Stg}$		- 65 to 175	°C

### ELECTRICAL SPECIFICATIONS ( $T_J = 25\text{ °C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, V_R$	$I_R = 100\text{ }\mu\text{A}$	200	-	-	V
Forward voltage	$V_F$	$I_F = 8\text{ A}$	-	-	0.975	
		$I_F = 8\text{ A}, T_J = 150\text{ °C}$	-	-	0.895	
Reverse leakage current	$I_R$	$V_R = V_R\text{ rated}$	-	-	5	$\mu\text{A}$
		$T_J = 150\text{ °C}, V_R = V_R\text{ rated}$	-	-	250	
Junction capacitance	$C_T$	$V_R = 200\text{ V}$	-	25	-	pF
Series inductance	$L_S$	Measured lead to lead 5 mm from package body	-	8.0	-	nH

DYNAMIC RECOVERY CHARACTERISTICS ( $T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	$t_{rr}$	$I_F = 1.0\text{ A}$ , $di_F/dt = 50\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$	-	-	35	ns
		$I_F = 0.5\text{ A}$ , $I_R = 1.0\text{ A}$ , $I_{REC} = 0.25\text{ A}$	-	-	25	
		$T_J = 25\text{ }^{\circ}\text{C}$	-	20	-	
		$T_J = 125\text{ }^{\circ}\text{C}$	-	34	-	
Peak recovery current	$I_{RRM}$	$T_J = 25\text{ }^{\circ}\text{C}$	-	1.7	-	A
		$T_J = 125\text{ }^{\circ}\text{C}$	-	4.2	-	
Reverse recovery charge	$Q_{rr}$	$T_J = 25\text{ }^{\circ}\text{C}$	-	23	-	nC
		$T_J = 125\text{ }^{\circ}\text{C}$	-	75	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$		- 65	-	175	$^{\circ}\text{C}$
Thermal resistance, junction to case	$R_{thJC}$		-	-	3.0	$^{\circ}\text{C}/\text{W}$
Thermal resistance, junction to ambient	$R_{thJA}$		-	-	50	
Thermal resistance, case to heatsink	$R_{thCS}$	Mounting surface, flat, smooth and greased	-	0.5	-	
Weight			-	2.0	-	g
			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style D <sup>2</sup> PAK	MURB820			
		Case style TO-262	MURB820-1			

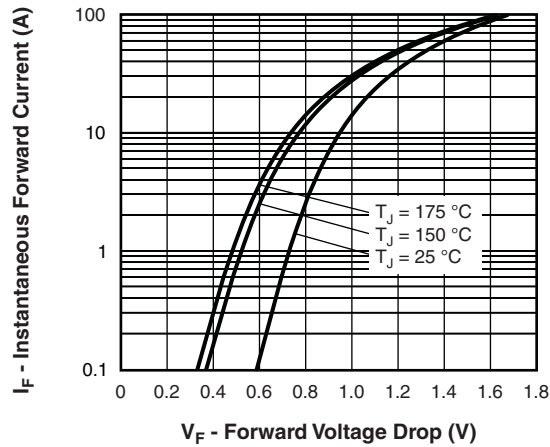


Fig. 1 - Typical Forward Voltage Drop Characteristics

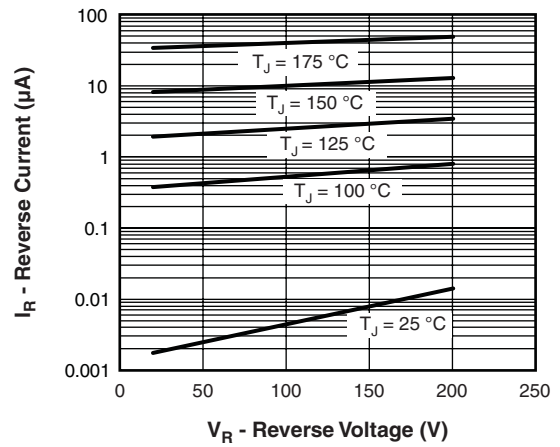


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

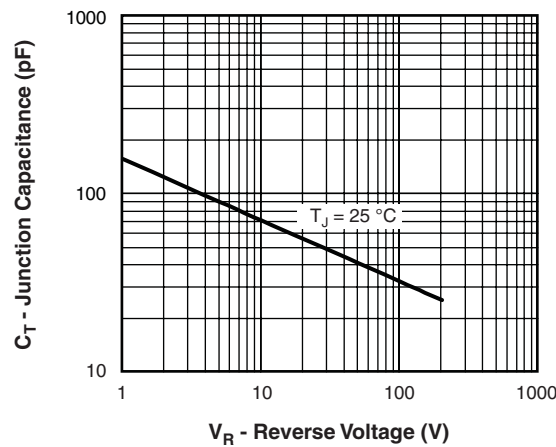


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

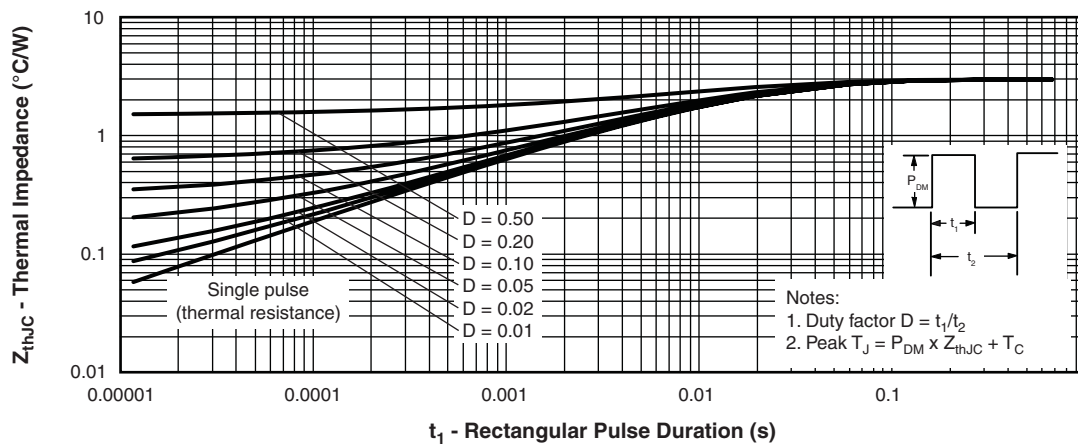


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics



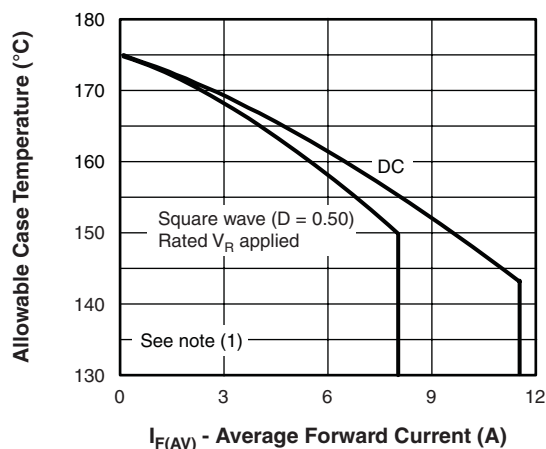


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

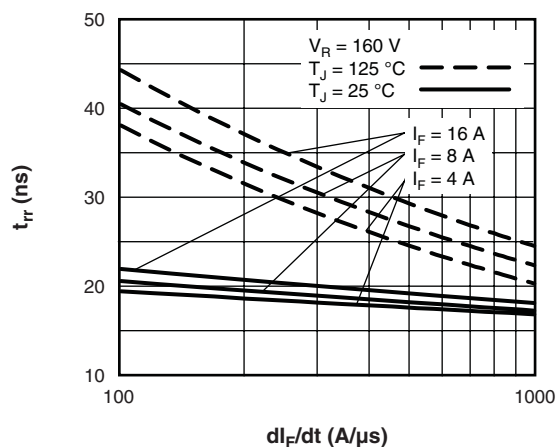


Fig. 7 - Typical Reverse Recovery Time vs.  $dI_F/dt$

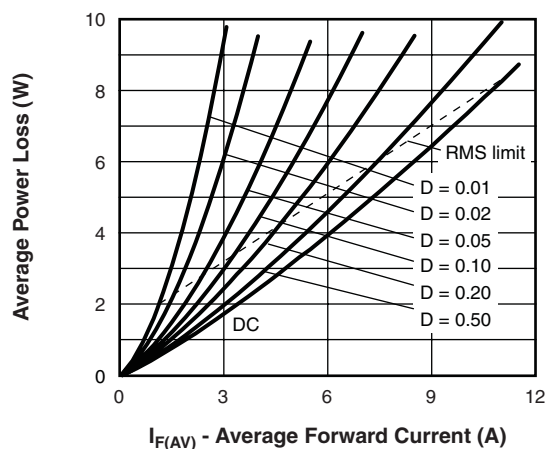


Fig. 6 - Forward Power Loss Characteristics

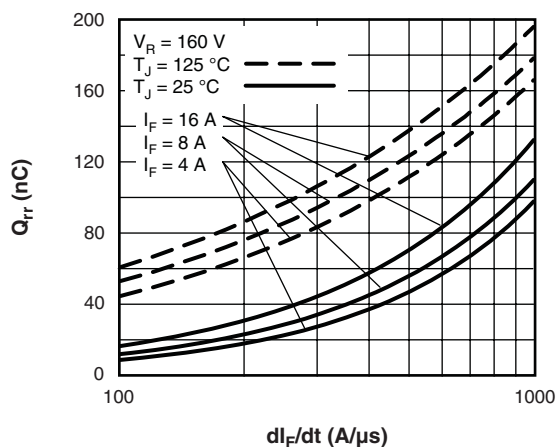


Fig. 8 - Typical Stored Charge vs.  $dI_F/dt$

## Note

- (1) Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;  
 $P_d$  = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  
 $P_{dREV}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = Rated  $V_R$

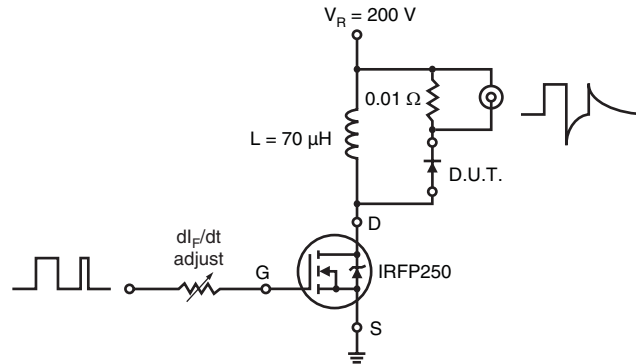


Fig. 9 - Reverse Recovery Parameter Test Circuit

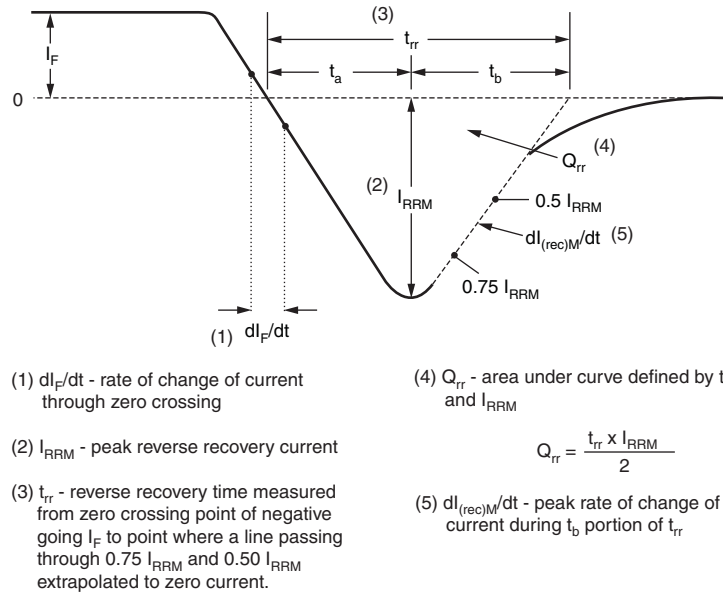


Fig. 10 - Reverse Recovery Waveform and Definitions

# MURB820/MURB820-1

Vishay High Power Products

Ultrafast Rectifier,  
8 A FRED Pt™



## ORDERING INFORMATION TABLE

Device code	MUR	B	8	20	-1	TRL	-
	①	②	③	④	⑤	⑥	⑦
①	- Ultrafast MUR series						
②	- B = D <sup>2</sup> PAK/TO-262						
③	- Current rating (8 = 8 A)						
④	- Voltage rating (20 = 200 V)						
⑤	• None = D <sup>2</sup> PAK						
	• -1 = TO-262						
⑥	• None = Tube (50 pieces)						
	• TRL = Tape and reel (left oriented, for D <sup>2</sup> PAK package)						
	• TRR = Tape and reel (right oriented, for D <sup>2</sup> PAK package)						
⑦	• None = Standard production						
	• PbF = Lead (Pb)-free						

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95014">http://www.vishay.com/doc?95014</a>
Part marking information	<a href="http://www.vishay.com/doc?95008">http://www.vishay.com/doc?95008</a>
Packaging information	<a href="http://www.vishay.com/doc?95032">http://www.vishay.com/doc?95032</a>



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